onsemi

<u>MOSFET</u> – Power, Single N-Channel 40 V, 2.2 mΩ, 142 A

NVTFS002N04CL

Features

- Small Footprint (3.3 x 3.3 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Capacitance to Minimize Driver Losses
- NVTFWS002N04CL Wettable Flanks Product
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	40	V
Gate-to-Source Voltage			V _{GS}	±20	V
Continuous Drain	Steady	$T_C = 25^{\circ}C$	I _D	142	А
Current R _{θJC} (Notes 1, 2, 3, 4)		T _C = 100°C		80	
Power Dissipation	State	$T_C = 25^{\circ}C$	PD	85	W
R _{θJC} (Notes 1, 2, 3)		$T_{C} = 100^{\circ}C$		27	
Continuous Drain		$T_A = 25^{\circ}C$	I _D	28	А
Current R _{θJA} (Notes 1, 3, 4)	Steady	T _A = 100°C		20	
Power Dissipation	State	T _A = 25°C	PD	3.2	W
R _{θJA} (Notes 1, 3)		T _A = 100°C		1.6	
Pulsed Drain Current	T _A = 25	°C, t _p = 10 μs	I _{DM}	706	А
Operating Junction and Storage Temperature Range			T _J , T _{stg}	–55 to +175	°C
Source Current (Body Diode)			۱ _S	70.4	А
Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 10.2 A)			E _{AS}	268	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS (Note 1)

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State (Note 3)	$R_{\theta JC}$	1.8	°C/W
Junction-to-Ambient - Steady State (Note 3)	$R_{\theta JA}$	46.5	

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

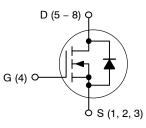
2. Psi (Ψ) is used as required per JESD51–12 for packages in which substantially less than 100% of the heat flows to single case surface.

3. Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.

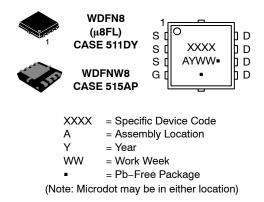
 Continuous DC current rating. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.

V _{(BR)DSS}	R _{DS(on)} MAX	I _D MAX
40 V	2.2 mΩ @ 10 V	142 A
40 V	3.5 mΩ @ 4.5 V	142 A

N-Channel



MARKING DIAGRAM



ORDERING INFORMATION

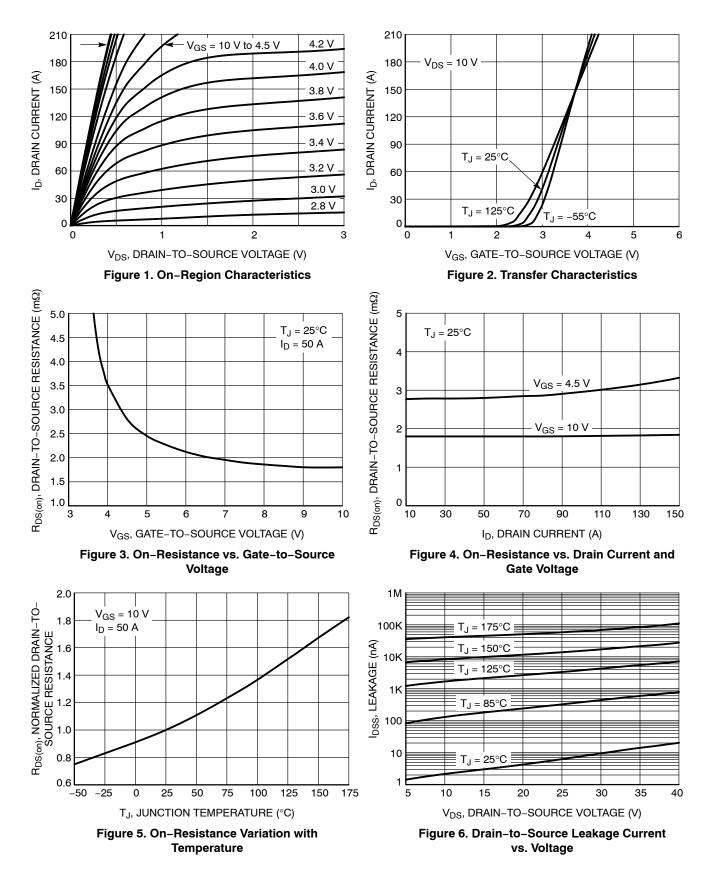
See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

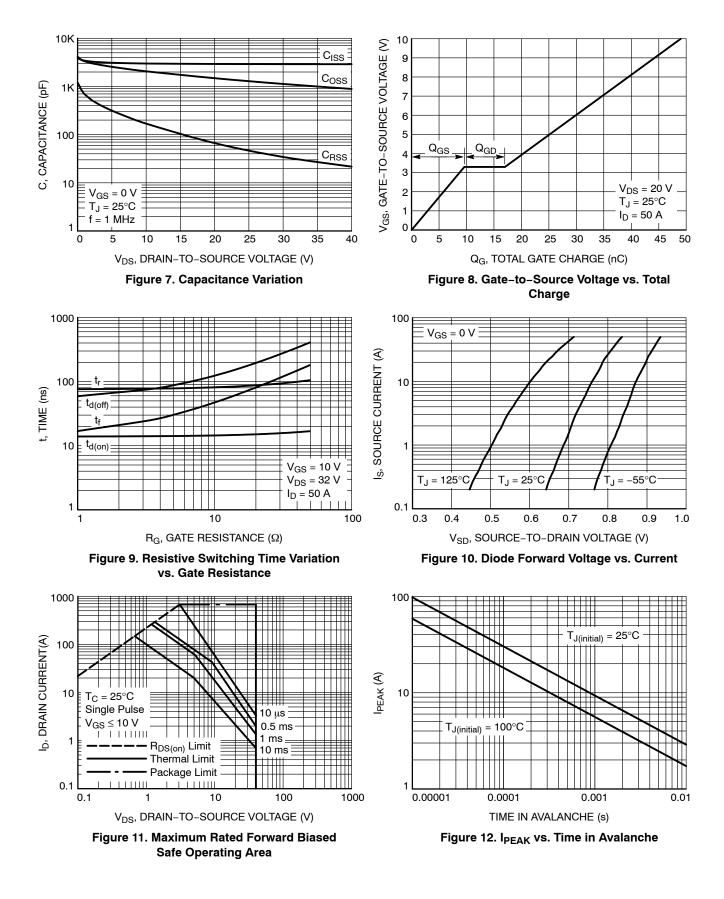
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS		•					
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I _D = 250 μ A		40			V
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V, V_{DS} = 40 V $ $T_{J} = 25^{\circ}C $ $T_{J} = 125^{\circ}C$				10	μA
					250	1	
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS} = 20 V				100	nA
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D = 90 \ \mu A$		1.2		2.0	V
Drain-to-Source On Resistance	R _{DS(on)}	V_{GS} = 10 V, I _D = 50 A V_{GS} = 4.5 V, I _D = 50 A			1.8	2.2	mΩ
					2.8	3.5	1
Forward Transconductance	9 FS	V _{DS} = 15 V, I	_D = 50 A			135	S
CHARGES AND CAPACITANCES							
Input Capacitance	C _{iss}	V_{GS} = 0 V, f = 1.0 MHz, V_{DS} = 25 V			2940		pF
Output Capacitance	C _{oss}				1260		-
Reverse Transfer Capacitance	C _{rss}				47		
Threshold Gate Charge	Q _{G(TH)}	V_{GS} = 10 V, V_{DS} = 20 V, I_D = 50 A V_{GS} = 10 V, V_{DS} = 20 V, I_D = 50 A			5.3		nC
Gate-to-Source Charge	Q_{GS}				9.6]
Gate-to-Drain Charge	Q_{GD}				7.4		1
Total Gate Charge	Q _{G(TOT)}				49		nC
SWITCHING CHARACTERISTICS (No	ie 6)						
Turn-On Delay Time	t _{d(on)}				14		ns
Rise Time	t _r	V _{GS} = 10 V, V _I	_{DS} = 32 V,		77		1
Turn-Off Delay Time	t _{d(off)}	V_{GS} = 10 V, V_{DS} = 32 V, I_D = 50 A			70		1
Fall Time	t _f				22		
DRAIN-SOURCE DIODE CHARACTER	ISTICS						
Forward Diode Voltage	V _{SD}	$V_{GS} = 0 V,$ $I_{S} = 50 A$	$T_J = 25^{\circ}C$		0.84	1.2	V
			T _J = 125°C		0.72		
Reverse Recovery Time	t _{RR}	V_{GS} = 0 V, dI_S/dt = 100 A/µs, I_S = 50 A			54		ns
Charge Time	t _a				24		1
Discharge Time	t _b				30		1
Reverse Recovery Charge	Q _{RR}				43		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 5. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%. 6. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

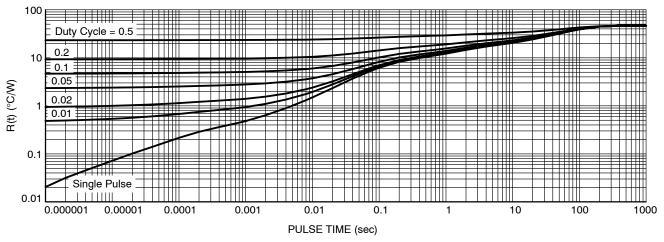


Figure 13. Thermal Characteristics

DEVICE ORDERING INFORMATION

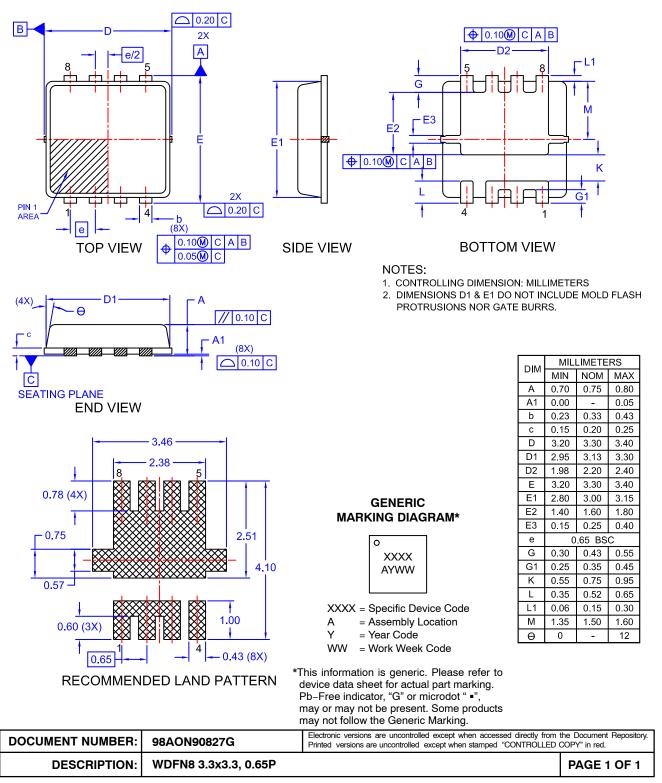
Device	Marking	Package	Shipping [†]
NVTFS002N04CLTAG	02NL	WDFN8 (Pb-Free)	1500 / Tape & Reel
NVTFWS002N04CLTAG	02LW	WDFNW8 (Pb-Free, Wettable Flanks)	1500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



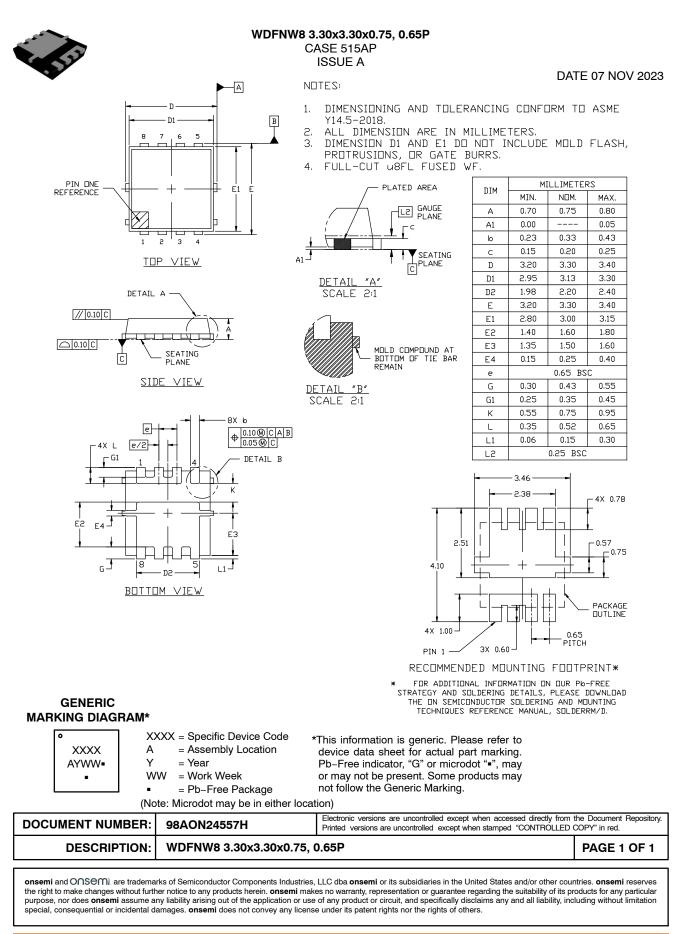
WDFN8 3.3x3.3, 0.65P CASE 511DY ISSUE A

DATE 21 AUG 2018



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